

P-Channel Enhancement Mode Power MOSFET

Description

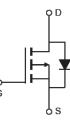
The RM25P30S8 uses advanced trench technology to provide excellent $R_{DS(ON)}$, This device is suitable for use as a load switch or power management.

General Features

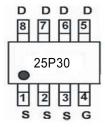
- V_{DS} = -30V,I_D = -25A
 R_{DS(ON)} <9mΩ @ V_{GS}=-10V
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- Power management
- Load switch



Schematic diagram



Marking and pin assignment



SOP-8 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
25P30	RM25P30S8	SOP-8	Ø330mm	12mm	2500

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	-25	А
Drain Current-Pulsed (Note 1)	I _{DM}	-70	A
Maximum Power Dissipation	PD	3.5	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient ^(Note 2)	$R_{ ext{ hetaJA}}$	36	°C /W

Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-30	-33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V,V _{GS} =0V	-	-	-1	μA

Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	·			•		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.0	-1.5	-2.5	V
	R _{DS(ON)}	V _{GS} =-10V, I _D =-15A	-	6.4	9	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-10A	-	8.3	14	
Forward Transconductance	g fs	V _{DS} =-10V,I _D =-15A	30	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	(-15)()(-0)(-	3960	-	PF
Output Capacitance	C _{oss}	- V _{DS} =-15V,V _{GS} =0V, - F=1.0MHz	-	486	-	PF
Reverse Transfer Capacitance	Crss		-	268	-	PF
Switching Characteristics (Note 4)	·			•		
Turn-on Delay Time	t _{d(on)}		-	20	-	nS
Turn-on Rise Time	tr	V _{DD} =-15V, ID=-10A,	-	13	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =-10V,R _{GEN} =3Ω	-	55	-	nS
Turn-Off Fall Time	t _f		-	21	-	nS
Total Gate Charge	Qg		-	65	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-15V,I _D =-10A,V _{GS} =-10V	-	12	-	nC
Gate-Drain Charge	Q _{gd}		-	14	-	nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-25A	-	-	-1.2	V

Notes

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

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RATING AND CHARACTERISTICS CURVES (RM25P30S8)

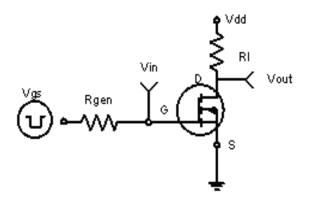
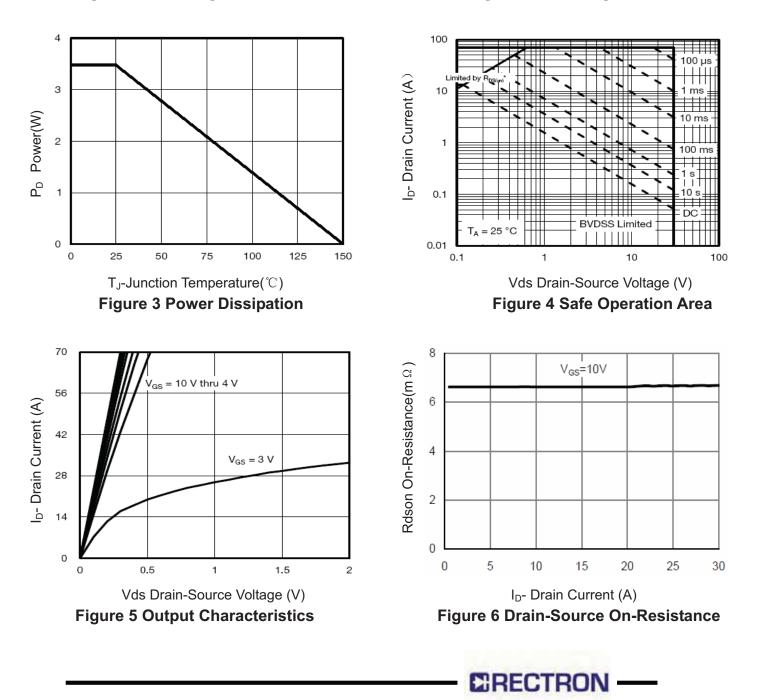


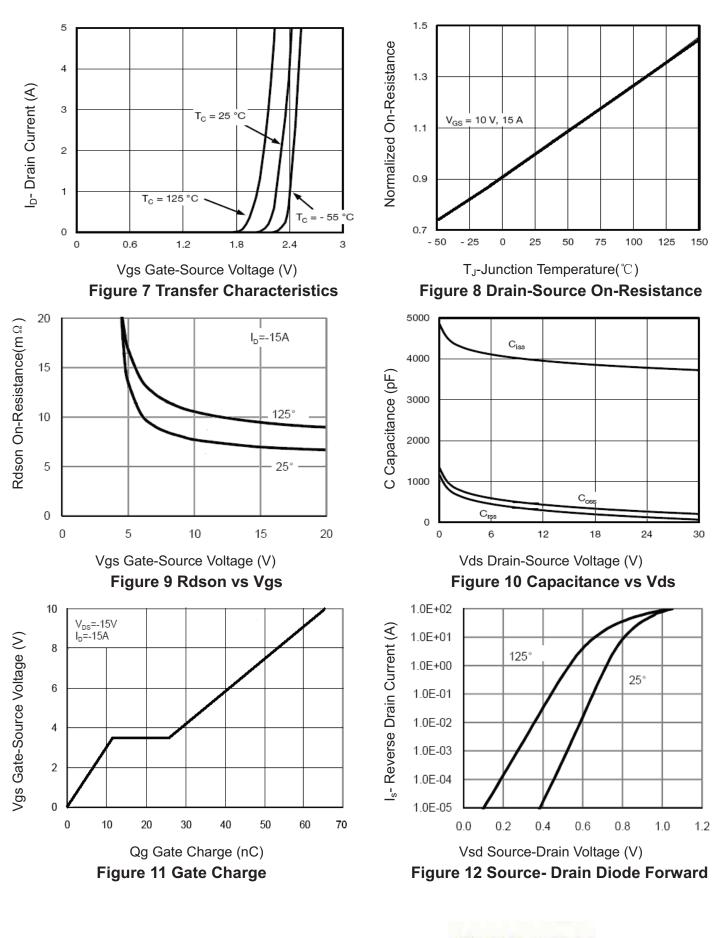
Figure 1 Switching Test Circuit



on off t t t_{d(on)} t_{d(off)} 90% 90% Vout **INVERTED** 10% 10% 90% V_{IN} 50% 50% 10% **PULSE WIDTH**

Figure 2 Switching Waveforms

RATING AND CHARACTERISTICS CURVES (RM25P30S8)



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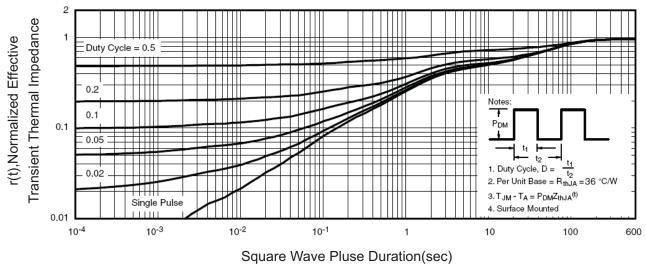
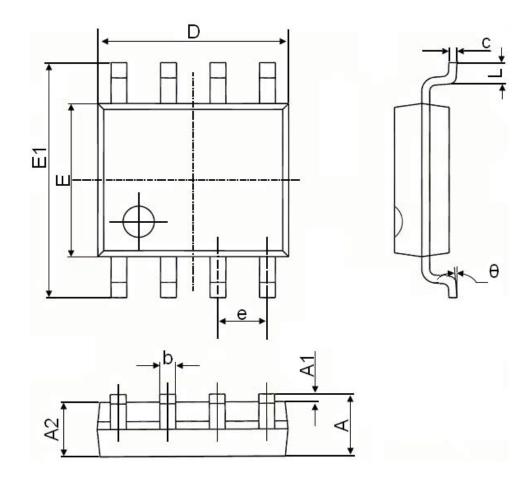


Figure 13 Normalized Maximum Transient Thermal Impedance



SOP-8 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270	D(BSC)	0.050	(BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



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